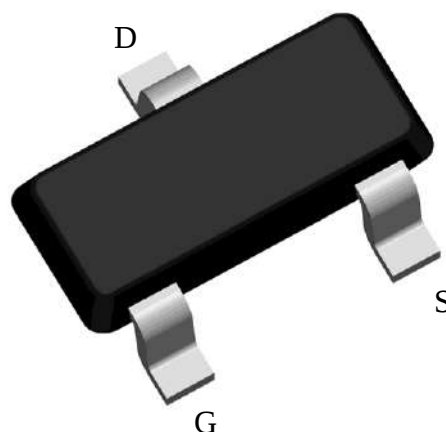


100V N-Channel Enhancement Mode MOSFET

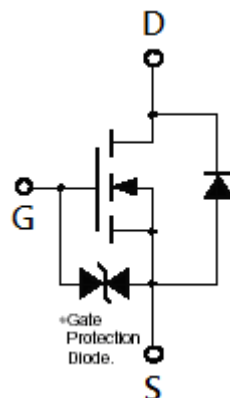
Features:

- Simple drive requirement
- Small package outline
- ESD protected gate
- Pb-free lead plating and halogen-free package

SOT-23



BV_{DSS}	100V
$I_D @ T_A=25^{\circ}C, V_{GS}=10V$	2A
$R_{DS(on)} @ V_{GS}=10V, I_D=1.7A$	127m Ω (typ)
$R_{DS(on)} @ V_{GS}=4.5V, I_D=1.7A$	160m Ω (typ)



G : Gate S : Source D : Drain

Ordering Information

Device	Package	Shipping
KW2328E	SOT-23 (Pb-free lead plating and halogen-free package)	3000 pcs / Tape & Reel

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	
Continuous Drain Current @ TA=25°C, V _{GS} =10V (Note 3)	I _D	2	A
Continuous Drain Current @ TA=70°C, V _{GS} =10V (Note 3)		1.6	
Pulsed Drain Current (Notes 1, 2)	I _{DM}	10	
Maximum Power Dissipation@ TA=25°C (Note 3)	P _D	1.25	W
Maximum Power Dissipation@ TA=70°C (Note 3)		0.8	
Operating Junction and Storage Temperature Range	T _j ; T _{stg}	-55~+150	°C

Note : 1. Pulse width limited by maximum junction temperature.

2. Pulse width ≤ 300μs, duty cycle ≤ 2%.

3. Surface mounted on 1 in² copper pad of FR-4 board; 270°C/W when mounted on minimum copper pad

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance, Junction-to-Ambient, max	R _{θJA}	100	°C/W
Thermal Resistance, Junction-to-Case, max	R _{θJC}	65	

Note : Surface mounted on 1 in² copper pad of FR-4 board; 270°C/W when mounted on minimum copper pad

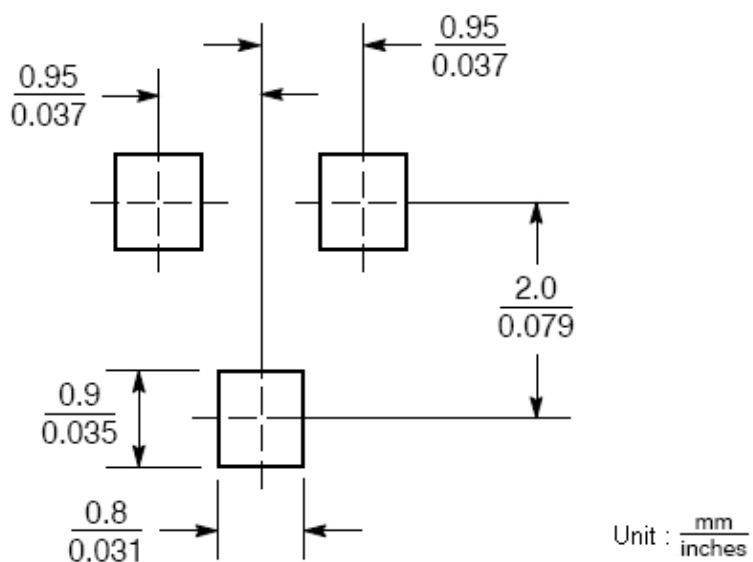
Electrical Characteristics (Tj=25°C, unless otherwise noted)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	100	-	-	V	V _{GS} =0V, I _D =250μA
V _{GS(th)}	1.0	-	2.5		V _{DS} =V _{GS} , I _D =250μA
I _{GSS}	-	-	±30	μA	V _{GS} =±16V, V _{DS} =0V
I _{DSS}	-	-	1		V _{DS} =80V, V _{GS} =0V
	-	-	10		V _{DS} =80V, V _{GS} =0V (T _j =85°C)
*R _{DS(ON)}	-	127	180	mΩ	V _{GS} =10V, I _D =1.7A
	-	160	235		V _{GS} =4.5V, I _D =1.7A
*G _{FS}	-	2.5	-	S	V _{DS} =10V, I _D =1A
Dynamic					
C _{iss}	-	248	-	pF	V _{DS} =30V, V _{GS} =0V, f=1MHz
C _{oss}	-	31	-		
C _{rss}	-	13	-		
t _{d(ON)}	-	4.6	10	ns	V _{DS} =30V, I _D =1A, V _{GS} =10V, R _G =6Ω
t _r	-	16.6	34		
t _{d(OFF)}	-	16	32		
t _f	-	14	28		

Qg	-	5.1	7.7	nC	V _{DS} =30V, I _D =1.7A, V _{GS} =10V
Qgs	-	1.1	-		
Qgd	-	0.7	-		
Source-Drain Diode					
*I _S	-	-	2	A	
*I _{SM}	-	-	10		
*V _{SD}	-	0.83	1.1	V	V _{GS} =0V, I _S =1.7A

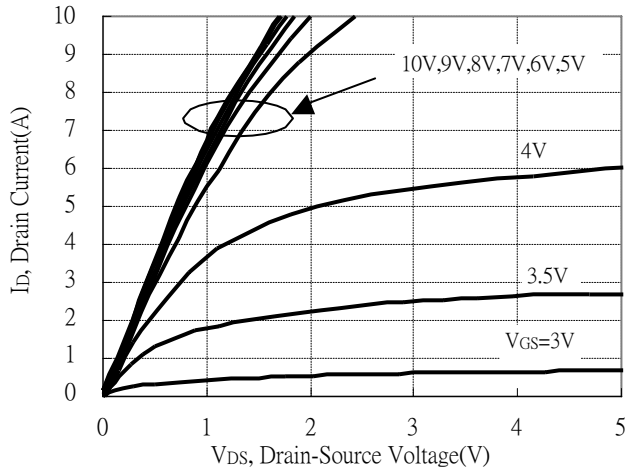
*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

Recommended Soldering Footprint

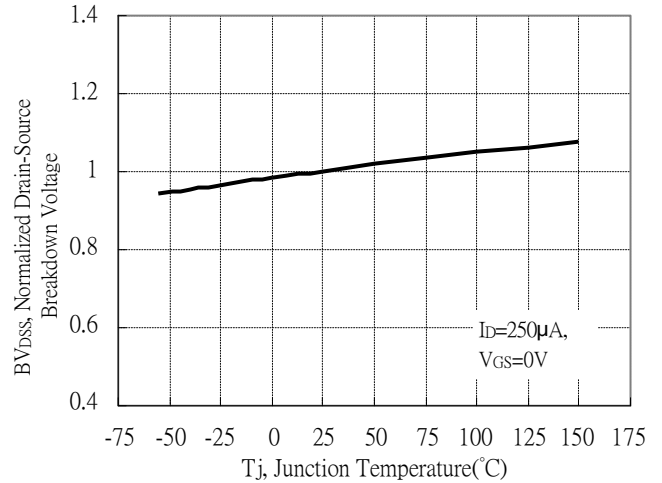


Typical Characteristics

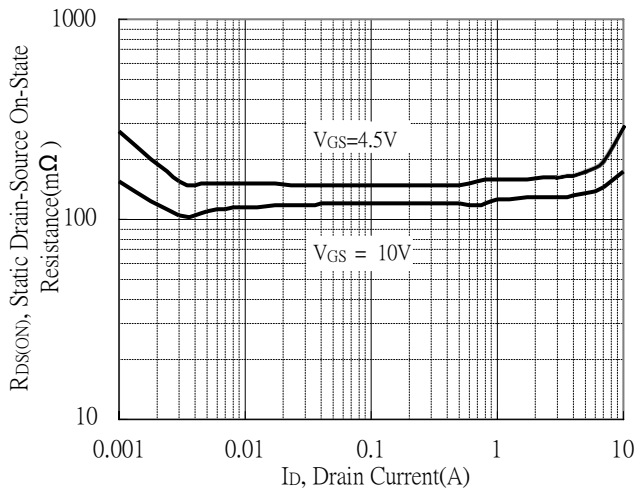
Typical Output Characteristics



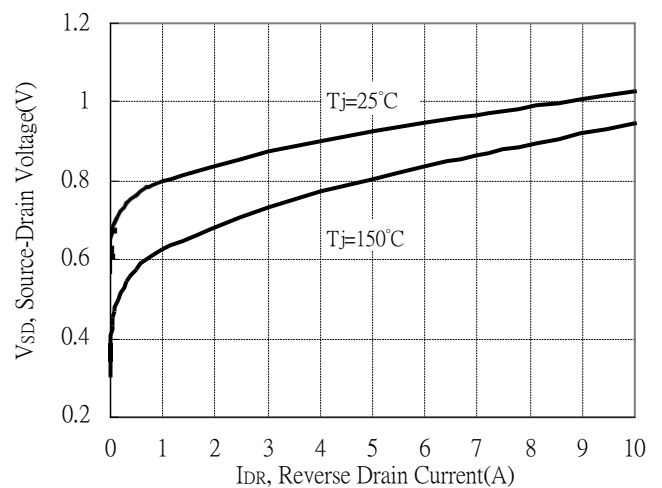
Breakdown Voltage vs Ambient Temperature



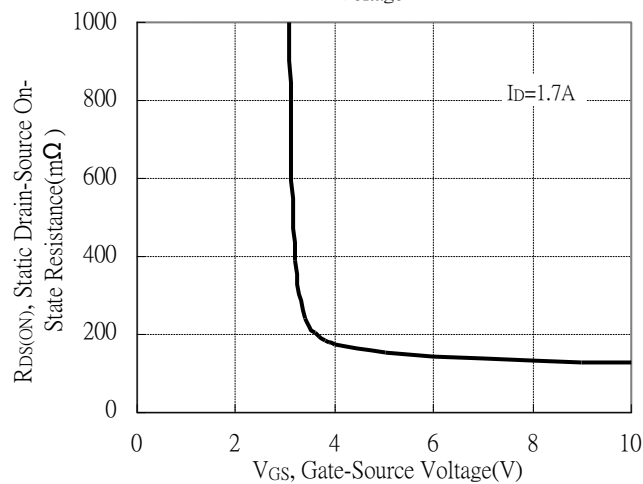
Static Drain-Source On-State resistance vs Drain Current



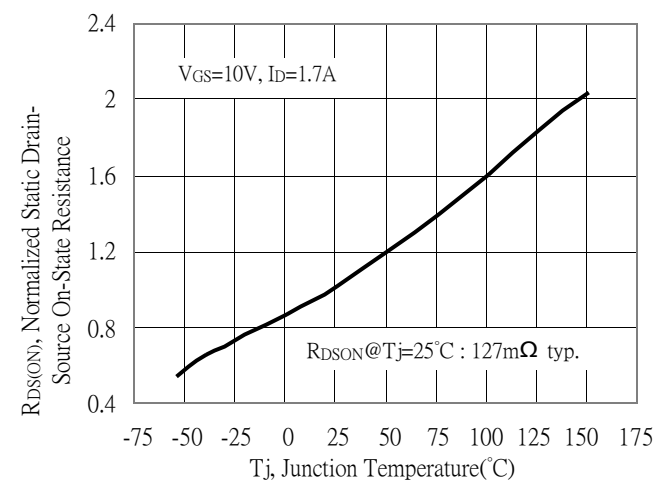
Reverse Drain Current vs Source-Drain Voltage



Static Drain-Source On-State Resistance vs Gate-Source Voltage

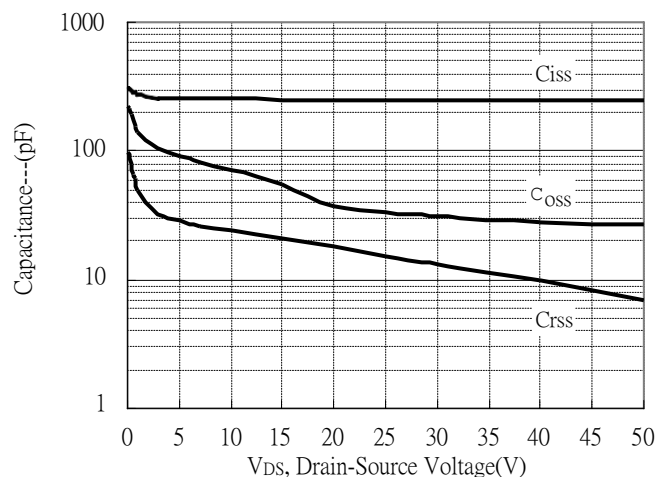


Drain-Source On-State Resistance vs Junction Temperature

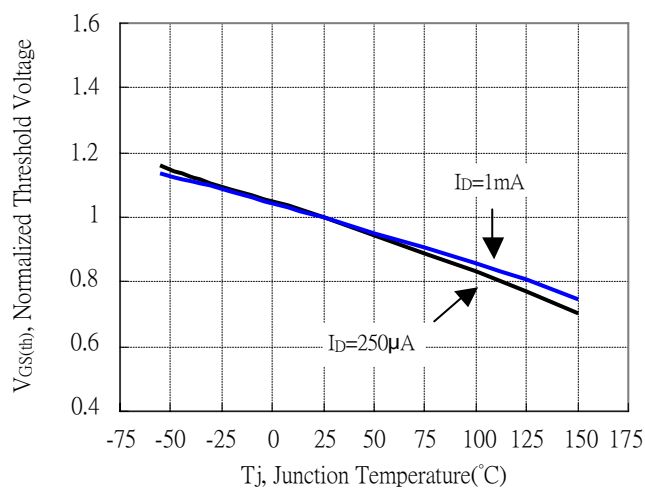


Typical Characteristics(Cont.)

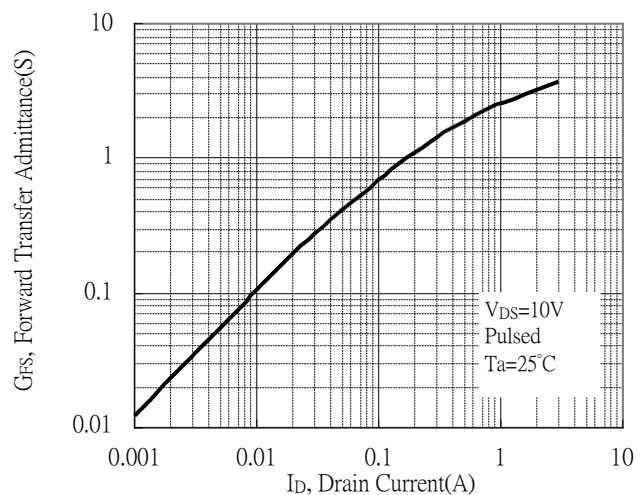
Capacitance vs Drain-to-Source Voltage



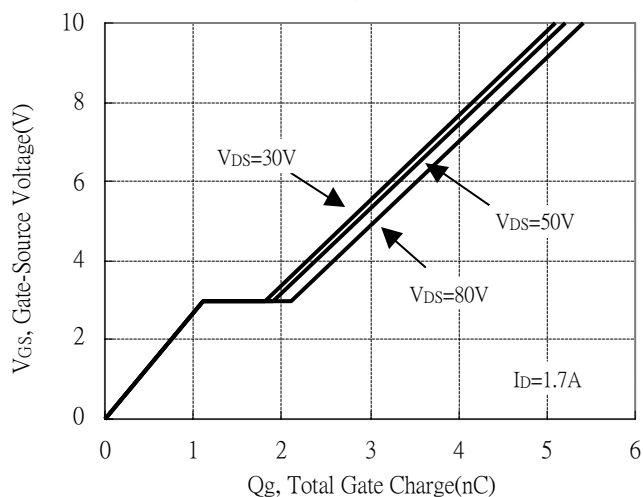
Threshold Voltage vs Junction Temperature



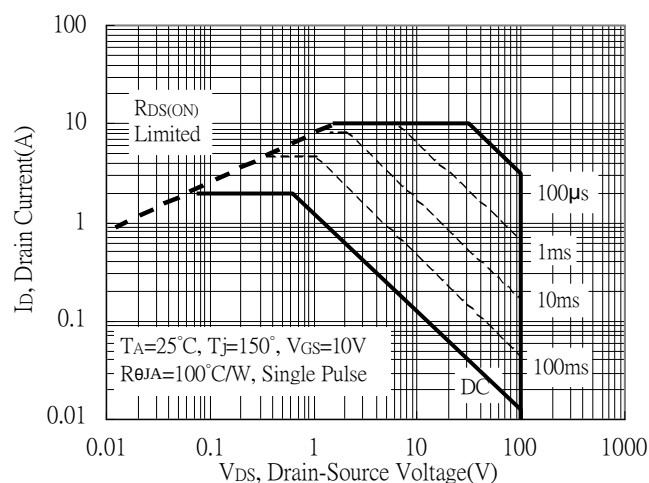
Forward Transfer Admittance vs Drain Current



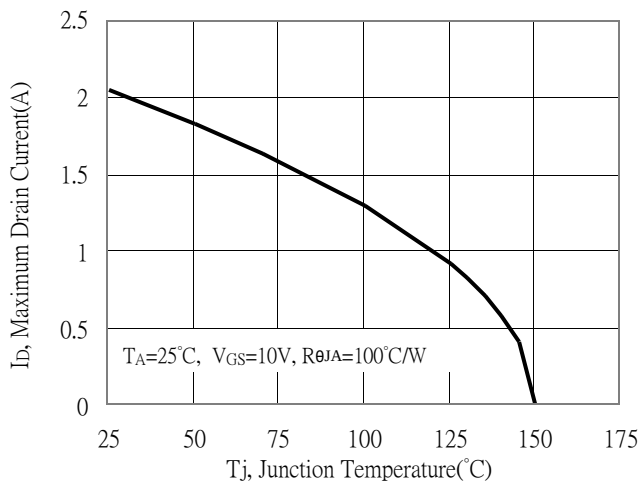
Gate Charge Characteristics



Maximum Safe Operating Area

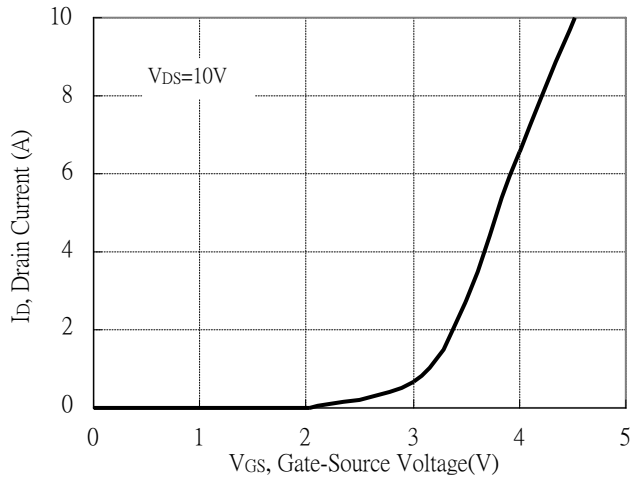


Maximum Drain Current vs Junction Temperature

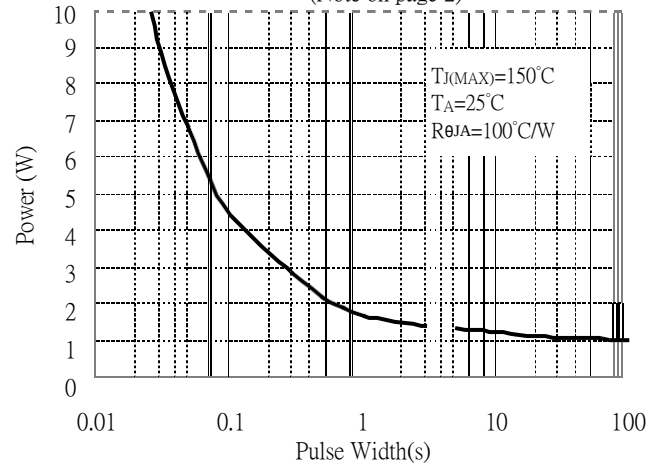


Typical Characteristics(Cont.)

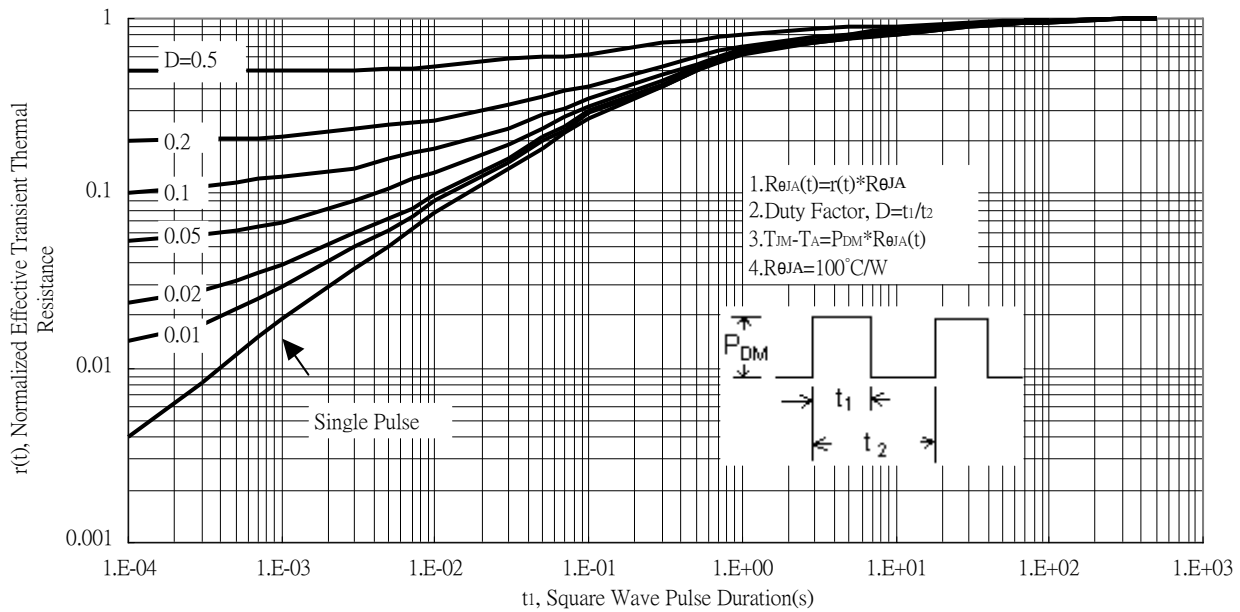
Typical Transfer Characteristics



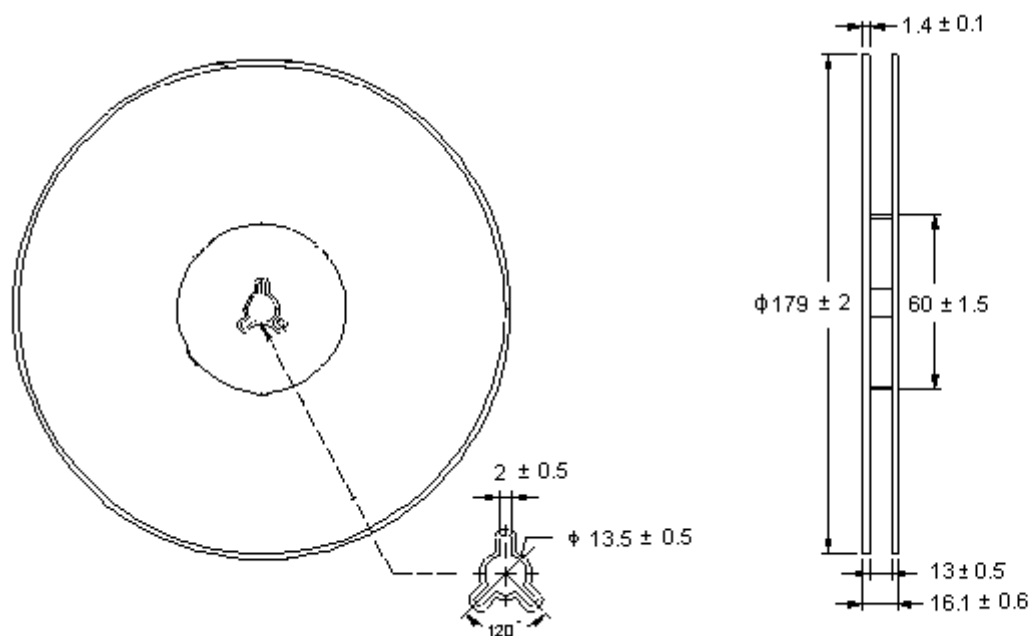
Single Pulse Power Rating, Junction to Ambient
 (Note on page 2)



Transient Thermal Response Curves

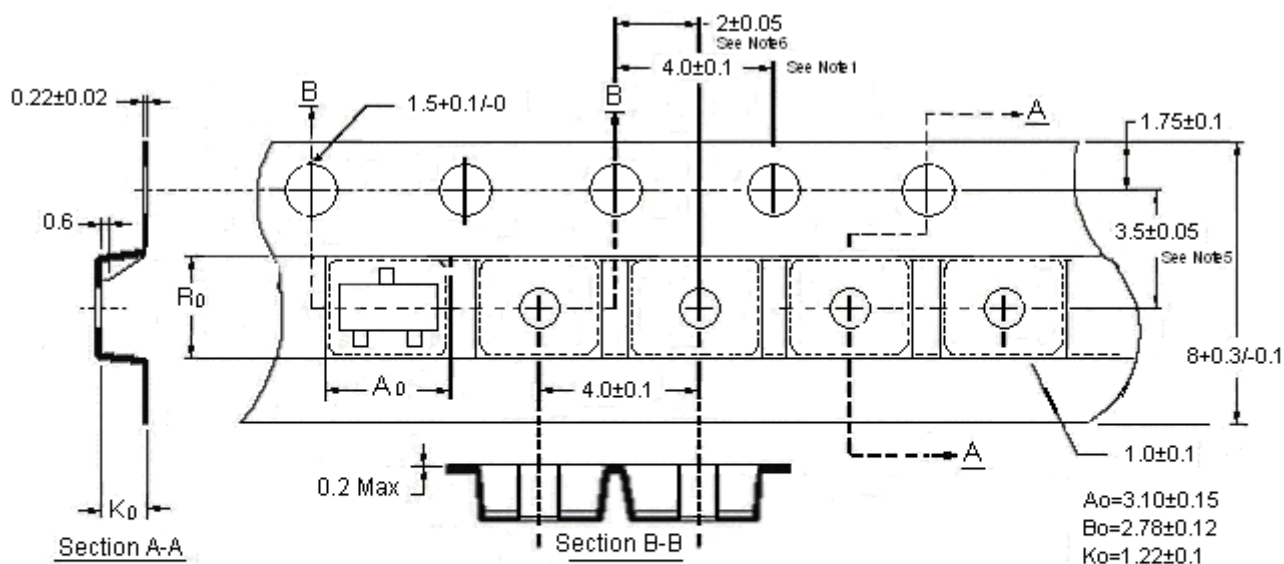


Reel Dimension

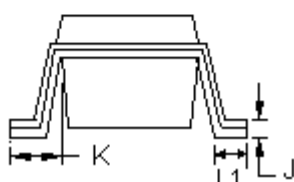
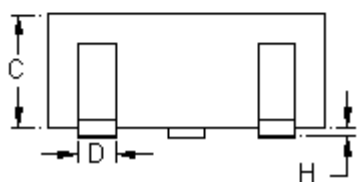
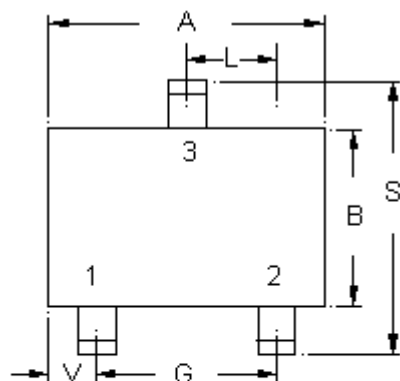


Unit: millimeter

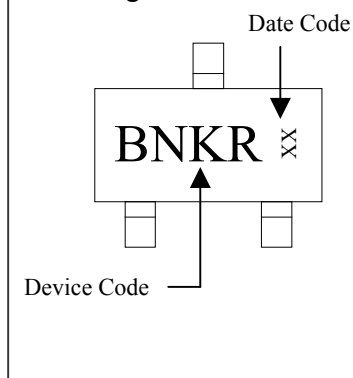
Carrier Tape Dimension



SOT-23 Dimension



Marking:



3-Lead SOT-23 Plastic
Surface Mounted Package

Style: Pin 1.Gate 2.Source 3.Drain

*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1102	0.1204	2.80	3.04	J	0.0032	0.0079	0.08	0.20
B	0.0472	0.0551	1.20	1.40	K	0.0118	0.0266	0.30	0.67
C	0.0335	0.0512	0.89	1.30	L	0.0335	0.0453	0.85	1.15
D	0.0118	0.0197	0.30	0.50	S	0.0830	0.1004	2.10	2.55
G	0.0669	0.0910	1.70	2.30	V	0.0098	0.0256	0.25	0.65
H	0.0000	0.0040	0.00	0.10	L1	0.0118	0.0197	0.30	0.50